# NSN 5961-00-245-6522

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**Inclosure Material:** 

Metal

**Overall Length:** 

0.450 inches

#### **Overall Diameter:**

0.875 inches

## **Mounting Facility Quantity:**

2

#### Internal Configuration:

Junction contact

## Electrode Internally-electrically Connected To Case:

Base

Internal Junction Configuration:

Npn

#### **Mounting Method:**

Unthreaded hole

## Features Provided:

Hermetically sealed case

#### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

700.0 breakdown voltage, collector-to-base, emitter open and 500.0 breakdown voltage, collector-to-emitter, base open and 6.0

breakdown voltage, emitter-to-base, collector open

#### **Current Rating Per Characteristic:**

Between 2.00 amperes source cutoff current and 3.50 amperes source cutoff current

#### **Power Rating Per Characteristic:**

100.0 watts small-signal input power, common-collector

## Maximum Operating Tempurature Per Measurement Point:

165.0 degrees celsius junction

#### **Terminal Type And Quantity:**

2 uninsulated wire lead and 1 case

#### **Specification Data:**

80131-release5607 professional/industrial association specification

#### Shelf Life:

N/a

## Unit Of Measure:

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#### Demilitarization:

No

#### Fiig:

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